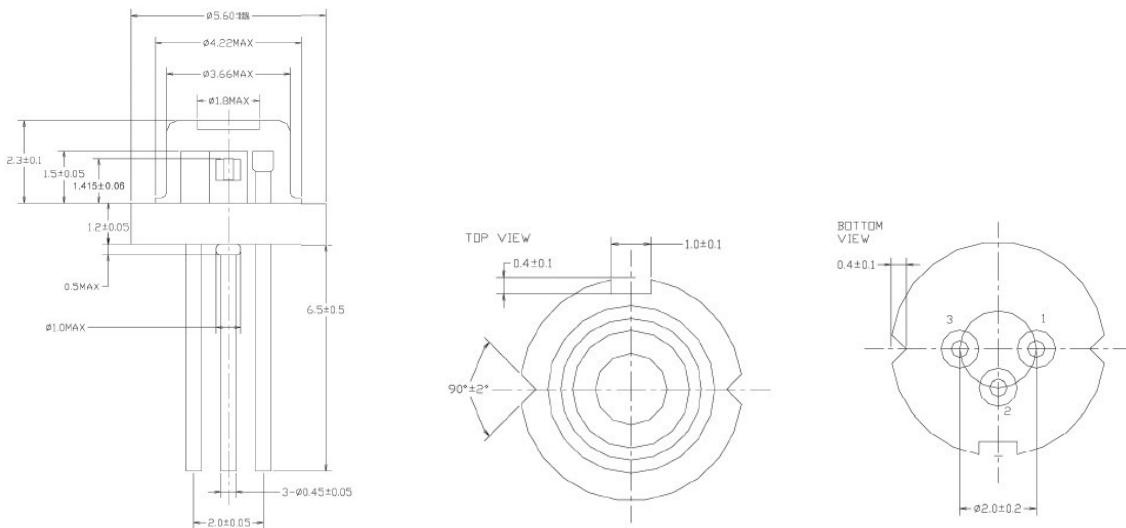


405nm Laser Diode 20mw

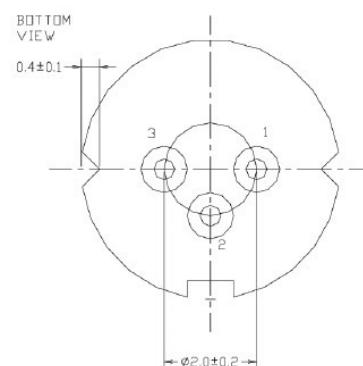
PARAMETER	SYMBOL	VALUE		UNIT		
Reverse Voltage	V_r	2.0		V		
Operating Temperature	T_{op}	0~+75		°C		
Storage Temperature	T_{stg}	-40 ~ +85		°C		
Lead soldering temperature (10 sec.)	T_{ls}	260		°C		
Features:	<ul style="list-style-type: none"> ☒ 405nm ☒ CW ☒ TO18 package 					
Applications:	<ul style="list-style-type: none"> ☒ Medical Cure ☒ Printing 					
Specifications						
		Min	Type	Max		
Center Wavelength@25°C		395nm	405nm	415nm		
Spectral Width (FWHM)		2.0nm				
Output Power		----	10mW	20mW		
Emitter		Single				
Beam Divergence (FWHM)		16° \perp x 6°//	19° \perp x 8.5°//	23° \perp x 12°//		
Monitor Current		----	----	----		
PD Reverse Voltage		----				
PD Forward Current		----				
Slope Efficiency		0.7mW/mA	1.1mW/mA	----		
Threshold Current (Typ.)		----	26mA	50mA		
Operating Current (Typ.)		----	35mA	60mA		
Operating Voltage		4.8V		5.6V		
Package Style	TO18(5.6mm)					



TO18(5.6mm) Package View



PIN Bottom View:



1	LD(-)
2	GND
3	LD(+)

Electrically shorten LD module and store in non-extreme conditions.

Suggest using the constant current power supply.

